

3.0Amp Schottky Barrier Rectifiers
Reverse Voltage 150V and 200V Forward Current 3A
SB3150 and SB3200

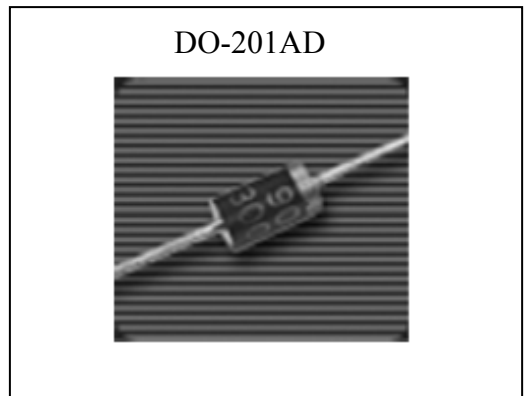
Features

- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

Mechanical Data

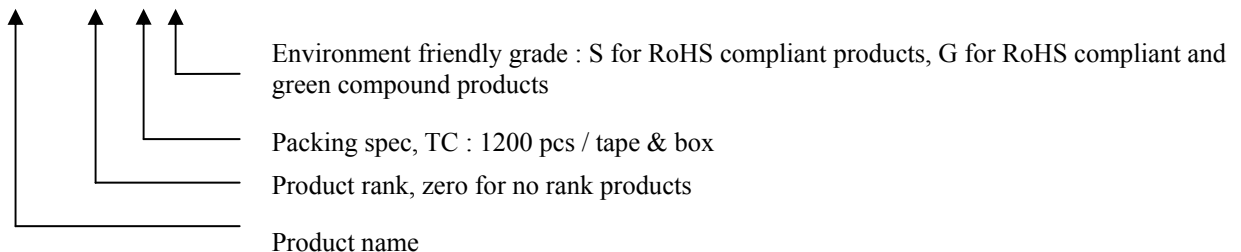
- Case : JEDEC DO-201AD molded plastic body
- Epoxy : UL94V-0 rate flame retardant
- Terminals: Plated axial leads, solderable per MIL-STD-202, method 208 guaranteed
- Polarity: Color band denotes cathode end.
- Mounting Position : Any.
- Weight: 1.10 grams

Outline



Ordering Information

| Device | Package | Shipping |
|----------------|---|-----------------------|
| SB3150- 0-TC-G | DO-201AD | 1200 pcs / Tape & Box |
| SB3200- 0-TC-G | (Pb-free lead plating and halogen-free package) | |





Maximum Ratings and Electrical Characteristics

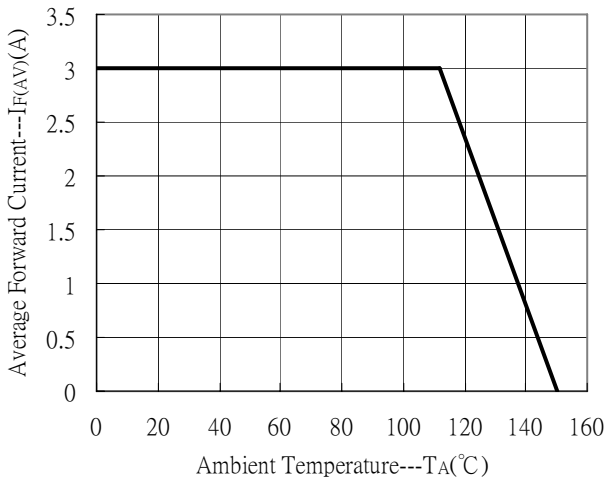
(Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%)

| Parameter | Symbol | Type | | Units |
|---|--------------------|-----------------------|--------|-------|
| | | SB3150 | SB3200 | |
| Maximum repetitive peak reverse voltage | V _{RRM} | 150 | 200 | V |
| Maximum RMS voltage | V _{RMS} | 105 | 140 | V |
| Maximum DC blocking voltage | V _{DC} | 150 | 200 | V |
| Maximum instantaneous forward voltage at 3A ¹ | V _F | 0.89 | | V |
| Maximum average forward rectified current | I _{F(AV)} | 3 | | A |
| Peak forward surge current @8.3ms single half sine wave superimposed on rated load (JEDEC method) | I _{FSM} | 80 | | A |
| Maximum DC reverse current at rated DC blocking voltage ¹ | I _R | T _A =25°C | 0.5 | mA |
| | | T _A =100°C | 10 | |
| Typical junction capacitance | C _J | 250 | | pF |
| Typical thermal resistance | R _{θJA} | 20 | | °C/W |
| Operating junction temperature range | T _J | -55 ~ +150 | | °C |
| Storage temperature range | T _{STG} | -55 ~ +150 | | °C |

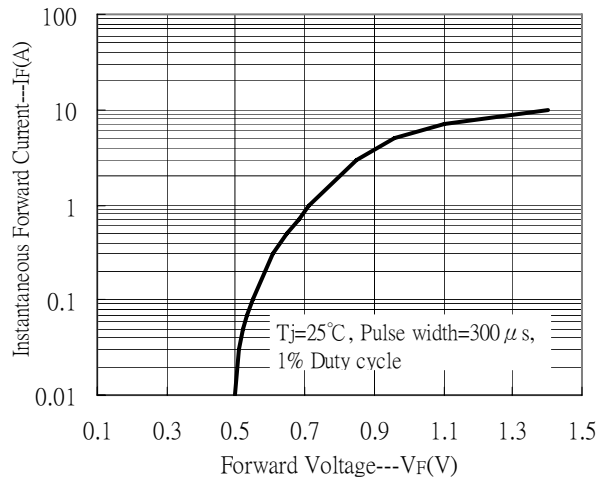
Note: 1.Pulse test: pulse width≤300μs, duty cycle≤2%

Characteristic Curves

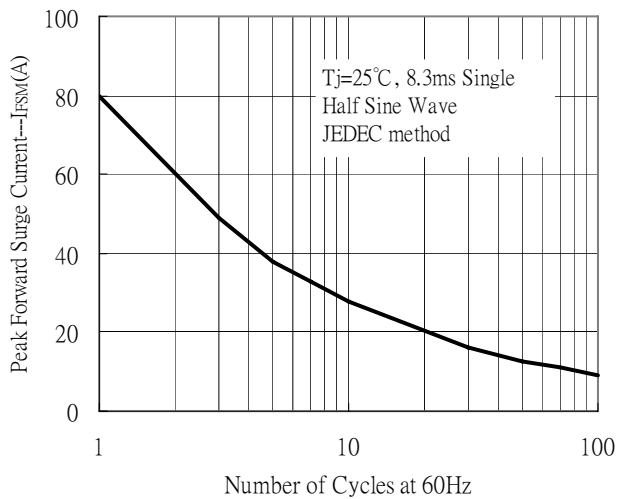
Forward Current Derating Curve



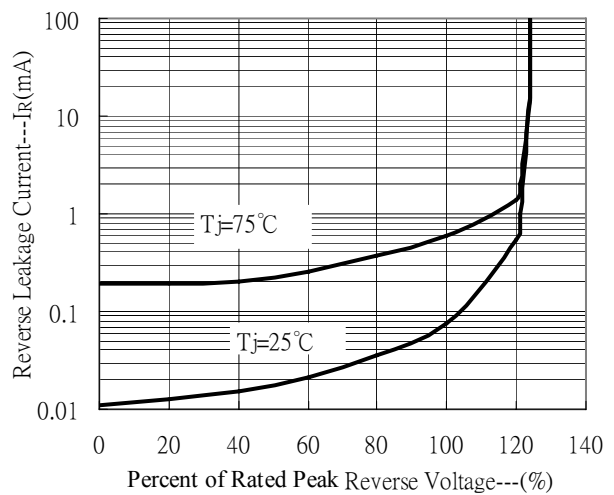
Forward Current vs Forward Voltage



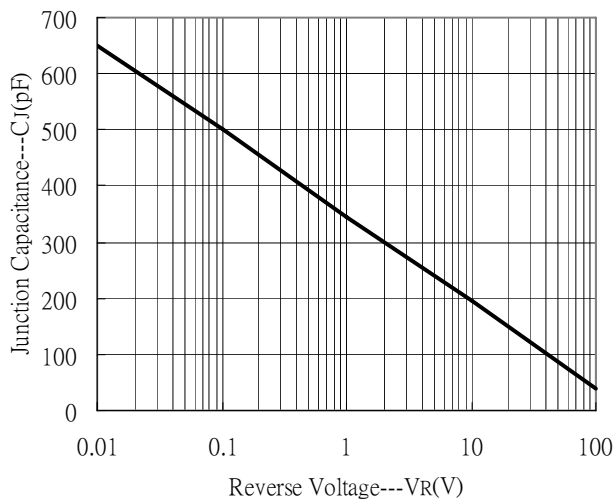
Maximum Non-Repetitive Forward Surge Current



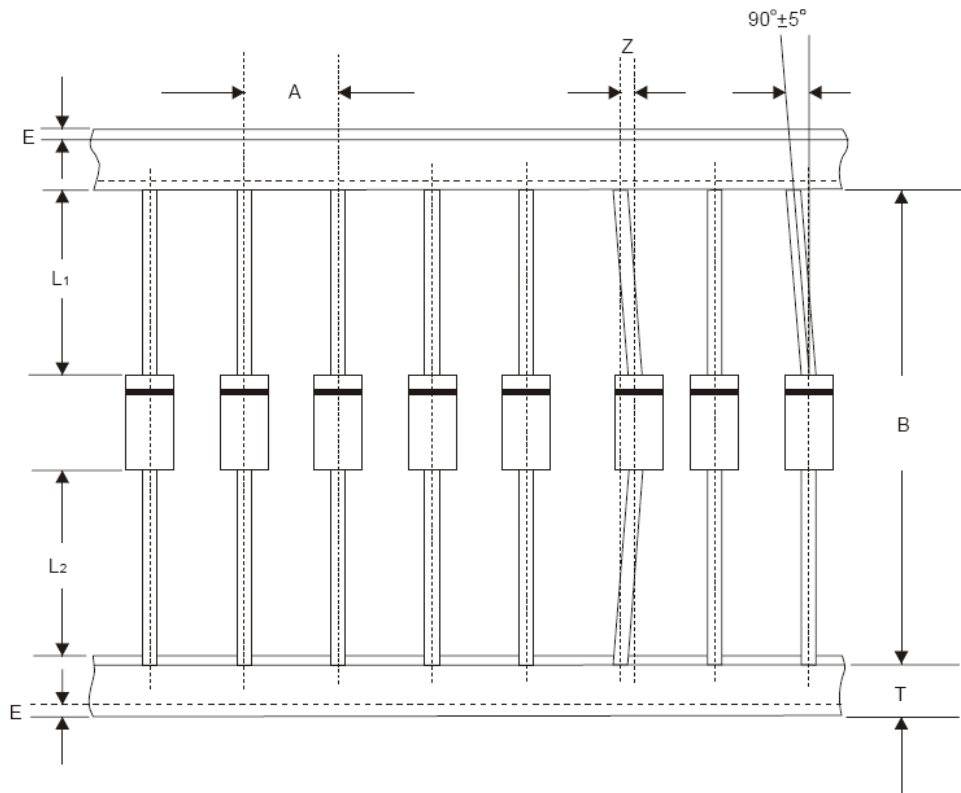
Reverse Leakage Current vs Reverse Voltage



Junction Capacitance vs Reverse Voltage



Taping Dimension



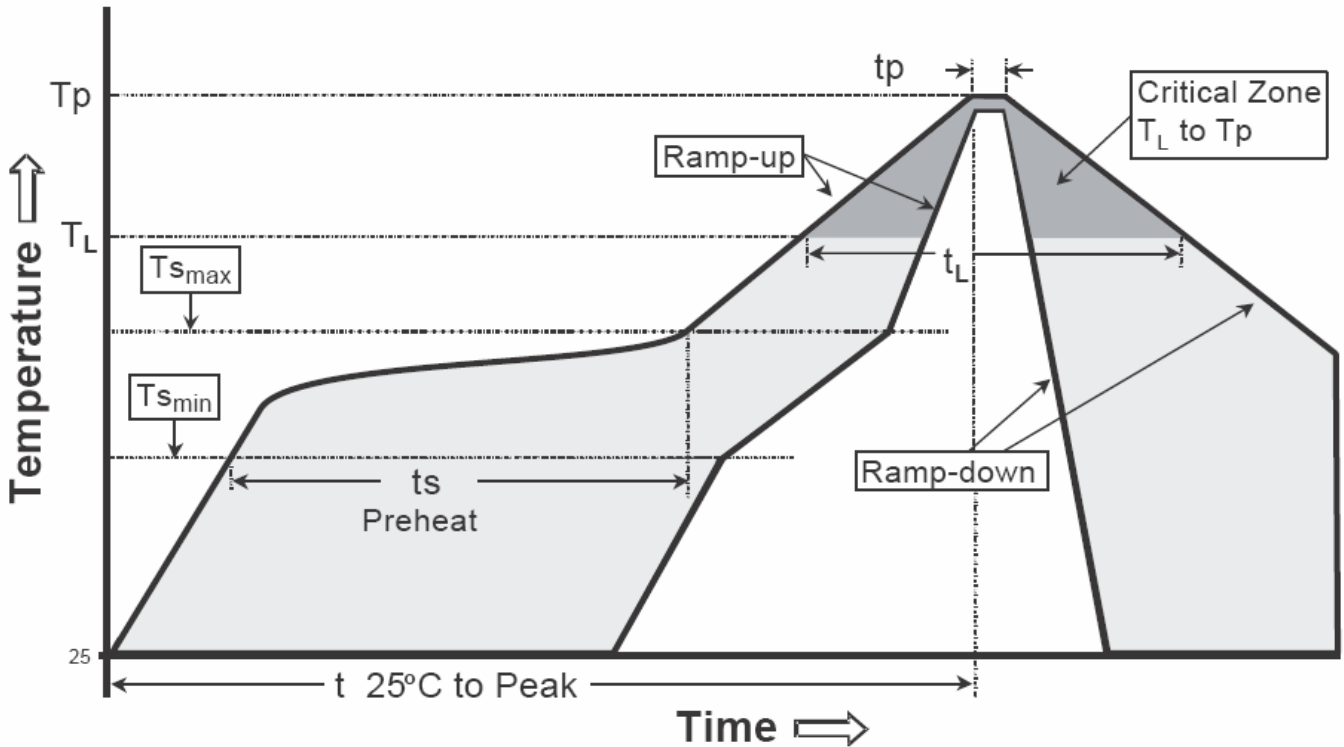
| ITEM | SYMBOL | SPECIFICATIONS (mm) | SPECIFICATIONS (inch) |
|---------------------|--------|--------------------------------------|---------------------------------------|
| Component pitch | A | 10 ±0.5 | 0.197±0.020 |
| Inner tape pitch | B | 52.4 ^{+0.5} _{-0.5} | 2.063 ^{+0.059} ₋₀ |
| Component alignment | Z | 1.2 max. | 0.048 max. |
| Tape width | T | 6.0±0.4 | 0.236±0.016 |
| Exposed adhesive | E | 0.8 max. | 0.032 max. |
| Body eccentricity | L1-L2 | 1.0 max. | 0.040 max. |

- NOTES: 1. Each component lead shall be sandwiched between tapes for a minimum of 3.2mm (0.126").
 2. The tolerance for cumulative pitch is 2.0mm/20 pitch.

Recommended wave soldering condition

| | | |
|-----------------|------------------|-----------------|
| Product | Peak Temperature | Soldering Time |
| Pb-free devices | 260 +0/-5 °C | 5 +1/-1 seconds |

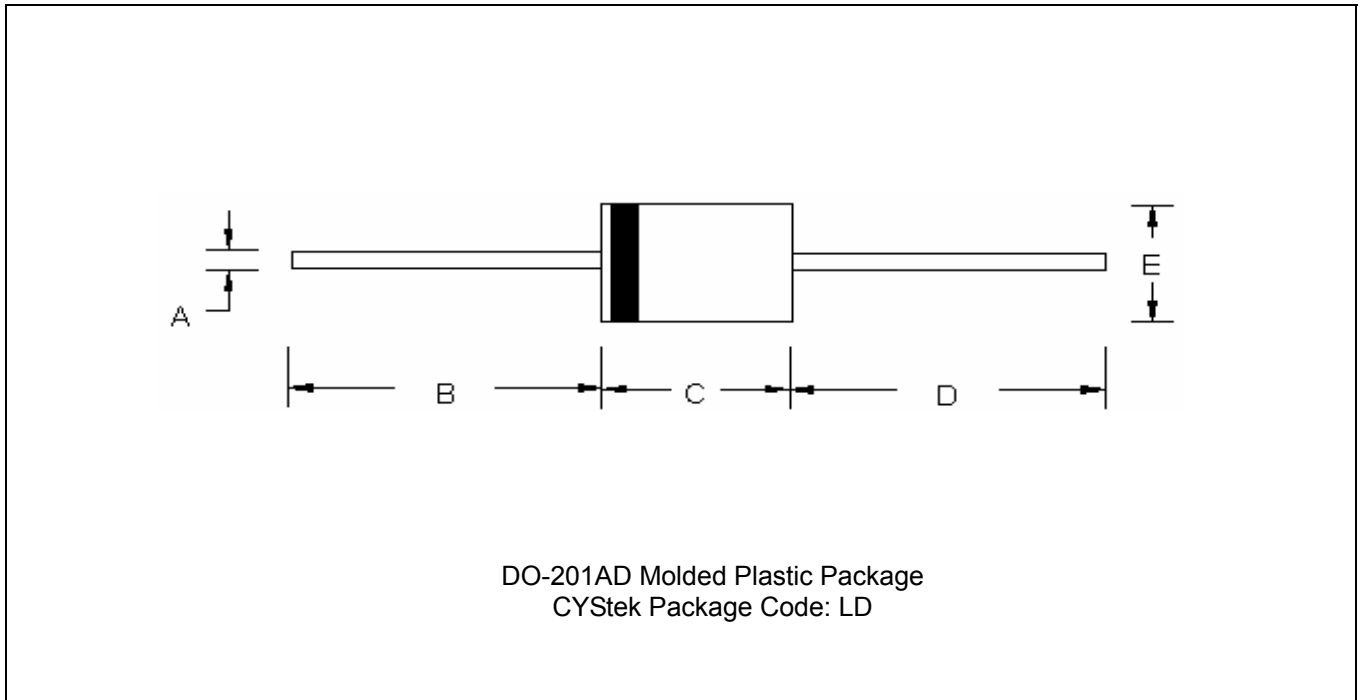
Recommended temperature profile for IR reflow



| Profile feature | Sn-Pb eutectic Assembly | Pb-free Assembly |
|--|-------------------------|------------------|
| Average ramp-up rate (Tsmax to Tp) | 3°C/second max. | 3°C/second max. |
| Preheat | | |
| -Temperature Min(Ts min) | 100°C | 150°C |
| -Temperature Max(Ts max) | 150°C | 200°C |
| -Time(ts min to ts max) | 60-120 seconds | 60-180 seconds |
| Time maintained above: | | |
| -Temperature (Tl) | 183°C | 217°C |
| - Time (tL) | 60-150 seconds | 60-150 seconds |
| Peak Temperature(Tp) | 240 +0/-5 °C | 260 +0/-5 °C |
| Time within 5°C of actual peak temperature(tp) | 10-30 seconds | 20-40 seconds |
| Ramp down rate | 6°C/second max. | 6°C/second max. |
| Time 25 °C to peak temperature | 6 minutes max. | 8 minutes max. |

Note : All temperatures refer to topside of the package, measured on the package body surface.

DO-201AD Dimension



| DIM | Inches | | Millimeters | | DIM | Inches | | Millimeters | |
|-----|--------|--------|-------------|-------|-----|--------|--------|-------------|-------|
| | Min. | Max. | Min. | Max. | | Min. | Max. | Min. | Max. |
| A | φ0.048 | φ0.052 | φ1.20 | φ1.30 | D | 1.000 | - | 25.40 | - |
| B | 1.000 | - | 25.40 | - | E | φ0.190 | φ0.210 | φ4.80 | φ5.30 |
| C | 0.285 | 0.375 | 7.20 | 9.50 | | | | | |

Notes : 1. Controlling dimension : millimeters.
 2. Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3. If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material :

- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guaranteed.
- Mold Compound : Epoxy resin family, flammability solid burning class: UL94V-0

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